

CD54HC257, CD74HC257, CD54HCT257

Data sheet acquired from Harris Semiconductor SCHS171D

November 1997 - Revised October 2003

High-Speed CMOS Logic Quad 2-Input Multiplexer with Three-State Non-Inverting Outputs

Features

- · Buffered Inputs
- Typical Propagation Delay (In to Output) = 12ns at V_{CC} = 5V, C_L = 15pF, T_A = 25°C
- Fanout (Over Temperature Range)
 - Standard Outputs............ 10 LSTTL Loads
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility, V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, $I_I \le 1\mu A$ at V_{OL} , V_{OH}

Description

The 'HC257 and 'HCT257 are quad 2-input multiplexers which select four bits of data from two sources under the control of a common Select Input (S). The Output Enable input (\overline{OE}) is active LOW. When \overline{OE} is HIGH, all of the outputs (1Y-4Y) are in the high impedance state regardless of

all other input conditions.

Moving data from two groups of registers to four common output buses is a common use of the 257. The state of the Select input determines the particular register from which the data comes. It can also be used as a function generator.

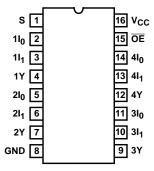
Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC257F3A	-55 to 125	16 Ld CERDIP
CD54HCT257F3A	-55 to 125	16 Ld CERDIP
CD74HC257E	-55 to 125	16 Ld PDIP
CD74HC257M	-55 to 125	16 Ld SOIC
CD74HC257MT	-55 to 125	16 Ld SOIC
CD74HC257M96	-55 to 125	16 Ld SOIC
CD74HCT257E	-55 to 125	16 Ld PDIP
CD74HCT257M	-55 to 125	16 Ld SOIC
CD74HCT257MT	-55 to 125	16 Ld SOIC
CD74HCT257M96	-55 to 125	16 Ld SOIC

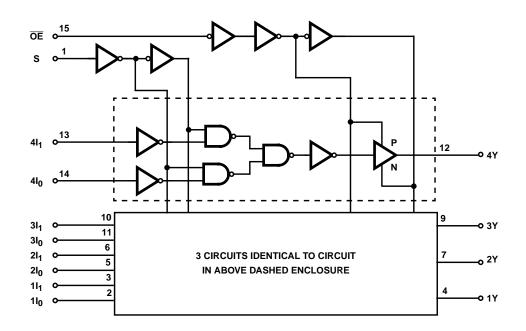
NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250.

Pinout

CD54HC257, CD54HCT257 (CERDIP) CD74HC257, CD74HCT257 (PDIP, SOIC) TOP VIEW



Functional Diagram



TRUTH TABLE

OUTPUT ENABLE	SELECT INPUT	DATA I	ОИТРИТ			
ŌĒ	S	l ₀	l ₀ l ₁			
Н	Х	Х	Х	Z		
L	L	L	Х	L		
L	L	Н	Х	Н		
L	Н	Х	L	L		
L	Н	Х	Н	Н		

H= High Voltage Level

L= Low Voltage Level

X= Don't Care

Z= High Impedance, OFF State

Absolute Maximum Ratings

DC Supply Voltage, V_{CC} -0.5V to 7V DC Input Diode Current, I_{IK} For $V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$ ± 20 mA DC Output Diode Current, I_{OK} For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$±20mA DC Drain Current, per Output, IO For $-0.5V < V_O < V_{CC} + 0.5V$±35mA DC Output Source or Sink Current per Output Pin, IO

Thermal Information

Thermal Resistance (Typical, Note 1)	θ_{JA} (°C/W)
E (PDIP) Package	. 67
M (SOIC) Package	
Maximum Junction Temperature	
Maximum Storage Temperature Range	-65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C
(SOIC - Lead Tips Only)	

Operating Conditions

Temperature Range, T _A 55°C to 125°C Supply Voltage Range, V _{CC}
HC Types2V to 6\
HCT Types
DC Input or Output Voltage, $V_1, V_0 \dots 0V$ to V_{CO}
Input Rise and Fall Time
2V
4.5V 500ns (Max
6V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

			ST ITIONS		25°C		-40°C T	O 85°C	-55°C T	O 125°C			
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS	
HC TYPES	HC TYPES												
High Level Input	V _{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	V	
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V	
				6	4.2	-	-	4.2	-	4.2	-	V	
Low Level Input	V _{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V	
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V	
				6	-	-	1.8	-	1.8	-	1.8	V	
High Level Output	V _{OH}	V _{IH} or	-0.02	2	1.9	-	-	1.9	-	1.9	-	V	
Voltage CMOS Loads		V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V	
				-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output	1		-6	4.5	3.98	-	-	3.84	-	3.7	-	V	
Voltage TTL Loads			-7.8	6	5.48	-	-	5.34	-	5.2	-	V	
Low Level Output	V _{OL}	V _{IH} or	0.02	2	-	-	0.1	-	0.1	-	0.1	V	
Voltage CMOS Loads		V_{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V	
			0.02	6	-	-	0.1	-	0.1	-	0.1	V	
Low Level Output	7		6	4.5	-	-	0.26	-	0.33	-	0.4	V	
Voltage TTL Loads			7.8	6	-	-	0.26	-	0.33	-	0.4	V	
Input Leakage Current	II	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μА	

DC Electrical Specifications (Continued)

			ST ITIONS			25°C		-40°C T	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Quiescent Device Current	Icc	V _{CC} or GND	0	6	-	-	8	-	80	-	160	μА
Three-State Leakage Current	l _{OZ}	V _{IL} or V _{IH}	-	6	-	-	±0.5	-	±5	-	±10	μА
HCT TYPES	•		•									•
High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	٧
High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-6	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			6	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lı	V _{CC} to GND	0	5.5	-	-	±0.1	-	±1	-	±1	μА
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μА
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI _{CC} (Note 2)	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μА
Three-State Leakage Current	loz	V _{IL} or V _{IH}	-	5.5	-	-	±0.5	-	±5	-	±10	μА

NOTE:

2. For dual-supply systems theoretical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

HCT Input Loading Table

INPUT	UNIT LOADS
Data	0.95
S	3
ŌĒ	0.6

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Specifications table, e.g., 360 μA max at $25^{o}C.$

Switching Specifications Input t_r , $t_f = 6ns$

		TEST		25	°C	-40°C TO 85°C	-55°C TO 125°C	
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	TYP	MAX	MAX	MAX	UNITS
HC TYPES								
Propagation Delay In to Y	t _{PLH} , t _{PHL}	$C_L = 50pF$	2	-	150	190	225	ns
III to 1			4.5	•	30	38	45	ns
		C _L = 15pF	5	12	-	-	-	ns
		CL = 50pF	6	-	26	33	38	ns
Propagation Delay	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	175	220	265	ns
S to Y			4.5	-	35	44	53	ns
		C _L = 15pF	5	14	-	-	-	ns
		CL = 50pF	6	-	30	37	45	ns
Propagation Delay	t _{PLZ} , t _{PHZ} ,	CL = 50pF	2	-	150	190	225	ns
OE to Y	t _{PZL} , t _{PZH}	C _L = 50pF	4.5	-	30	38	45	ns
		C _L = 15pF	5	12	-	-	-	ns
		CL = 50pF	6	-	26	33	38	ns
Output Transition Times	t _{TLH} , t _{THL}	C _L = 50pF	2	-	60	75	90	ns
			4.5	-	12	15	18	ns
			6	-	10	13	15	ns
Input Capacitance	CI	-	-	-	10	10	10	pF
Three-State Output Capacitance	CO	-	-	-	20	20	20	pF
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	45	-	-	-	pF
HCT TYPES					!			
Propagation Delay	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	33	41	50	ns
In to Y		C _L = 15pF	5	13	-	-	-	ns
Propagation Delay	t _{PZL} , t _{PZH}	C _L = 50pF	4.5	-	38	48	57	ns
S to Y		C _L = 15pF	5	12	-	-	-	ns
Propagation Delay	t _{PLZ} , t _{PHZ}	C _L = 50pF	4.5	-	30	38	45	ns
OE to Y		C _L = 15pF	5	16	-	-	-	ns
Output Transition Times	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	12	15	18	ns
Input Capacitance	C _I	-	-	-	10	10	10	pF
Three-State Output Capacitance	CO	-	-	-	20	20	20	pF
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	45	-	-	-	pF

- 3. C_{PD} is used to determine the dynamic power consumption, per multiplexer. 4. $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where f_i = Input Frequency, C_L = Output Load Capacitance, V_{CC} = Supply Voltage.

Test Circuits and Waveforms

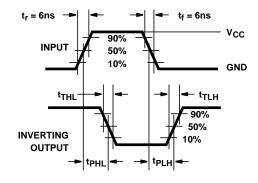


FIGURE 1. HC TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

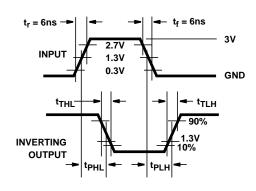


FIGURE 2. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

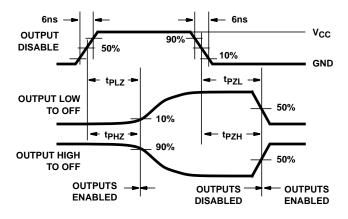


FIGURE 3. HC THREE-STATE PROPAGATION DELAY WAVEFORM

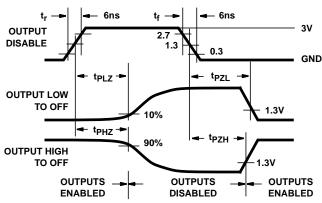
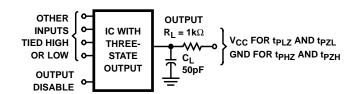


FIGURE 4. HCT THREE-STATE PROPAGATION DELAY WAVEFORM



NOTE: Open drain waveforms t_{PLZ} and t_{PZL} are the same as those for three-state shown on the left. The test circuit is Output $R_L = 1k\Omega$ to V_{CC} , $C_L = 50pF$.

FIGURE 5. HC AND HCT THREE-STATE PROPAGATION DELAY TEST CIRCUIT

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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
						(4)	(5)		
5962-8970501EA	Active	Production	CDIP (J) 16	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8970501EA CD54HCT257F3A
CD54HC257F3A	Active	Production	CDIP (J) 16	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8512401EA CD54HC257F3A
CD54HC257F3A.A	Active	Production	CDIP (J) 16	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8512401EA CD54HC257F3A
CD54HCT257F3A	Active	Production	CDIP (J) 16	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8970501EA CD54HCT257F3A
CD54HCT257F3A.A	Active	Production	CDIP (J) 16	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8970501EA CD54HCT257F3A
CD74HC257E	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HC257E
CD74HC257E.A	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HC257E
CD74HC257M	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-55 to 125	HC257M
CD74HC257M96	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC257M
CD74HC257M96.A	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC257M
CD74HCT257E	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HCT257E
CD74HCT257E.A	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HCT257E
CD74HCT257M	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-55 to 125	HCT257M
CD74HCT257M96	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT257M
CD74HCT257M96.A	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT257M

⁽¹⁾ Status: For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

PACKAGE OPTION ADDENDUM

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(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF CD54HC257, CD54HCT257, CD74HC257, CD74HCT257:

Catalog: CD74HC257, CD74HCT257

Military: CD54HC257, CD54HCT257

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC257M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HCT257M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1



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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC257M96	SOIC	D	16	2500	340.5	336.1	32.0
CD74HCT257M96	SOIC	D	16	2500	353.0	353.0	32.0

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD74HC257E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC257E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC257E.A	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC257E.A	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT257E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT257E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT257E.A	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT257E.A	N	PDIP	16	25	506	13.97	11230	4.32

D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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